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## DS14C335

## +3.3V Supply TIA/EIA-232 3 x 5 Driver/Receiver

#### **General Description**

The DS14C335 is three driver, five receiver device which conforms to TIA/EIA-232-E and CCITT V.28 standard specifications. This device employs an internal DC-DC converter to generate the necessary output levels from a  $\pm$  3.3V power supply. A SHUTDOWN (SD) mode reduces the supply current to 10  $\mu\text{A}$  maximum. In the SD mode, one receiver is active, allowing ring indicator (RI) to be monitored. PC Board space consumption is minimized by the availability of Shrink Small Outline Packaging (SSOP).

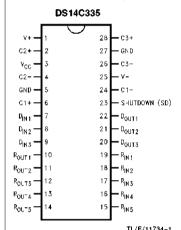
This device's low power requirement and small footprint makes it an ideal choice for Laptop and Notebook applica-

#### **Features**

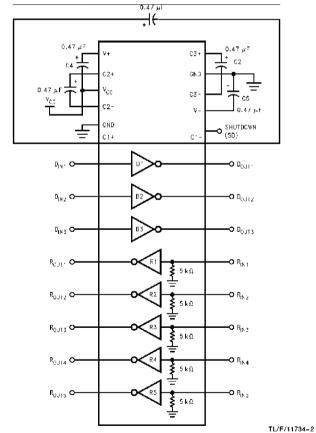
- Conforms to TIA/EIA-232-E and CCITT V.28 specifications
- Operates with single +3.3V power supply
- Low power requirement—I<sub>CC</sub> 20 mA maximum
- $\blacksquare$  SHUTDOWN mode—I $_{\rm CX}$  10  $\mu{\rm A}$  maximum
- One Receiver (R5) active during SHUTDOWN
- Operates up to 128 kbps—Lap-Link® Compatible
- Flow through pinout
- 4V/µs minimum Slew Rate guaranteed
- Inter-operates with +5V UARTs
- Available in 28-lead SSOP EIAJ Type II package

#### **Connection Diagram**

### **Functional Diagram**



Order Number DS14C335MSA or DS14C335TMSA See NS Package Number MSA28



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#### Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V<sub>CC</sub>) -0.3V to +6V $V^+$  Pin  $(V_{\rm CC} - 0.3V)$  to +14V V Pin + 0.3V to -14V Input Voltage (DIN, SD) -0.3V to +5.5V  $(V^{+} + 0.3V)$  to  $(V^{-} - 0.3V)$ Driver Output Voltage Receiver Input Voltage ±25V Receiver Output Voltage -0.3V to ( $V_{\rm CC}$  + 0.3V) Junction Temperature + 150°C Storage Temperature Range -65°C to +150°C Lead Temperature (Soldering 4 sec.) + 260°C Short Circuit Duration (DOUT) continuous Maximum Package Power Dissipation @ +25°C

# Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	3.0	3.6	٧
DC-DC Converter Capacitors (C1-C5)	0.47		μF
Operating Free Air Temperature (T <sub>A</sub> )			
DS14C335	0	+70	°C
DS14C335T	-40	+85	°C

#### **Electrical Characteristics**

ESD Rating (HBM, 1.5 kΩ, 100 pF)

Derate MSA Package 10.3 mW/°C above +25C

SSOP MSA Package

Over recommended operating conditions, SD = 0.8V, unless otherwise specified. (Notes 2, 3)

1286 mW

≥ 2.0 kV

Symbol	Parameter	Conditions			Min	Тур	Max	Units
DEVICE CH	IARACTERISTICS							
٧+	Positive Power Supply	No Load	D <sub>IN</sub> = 0.8V			+ 9.3		V
v-	Negative Power Supply	$C1-C5 = 0.47 \mu\text{F}$	D <sub>IN</sub> = 2.0V			-9.0		٧
loc	Supply Current	No Load	o Load			11.5	20	mA
I <sub>CX</sub>	SHUTDOWN Supply Current	$R_L = 3  k\Omega, SD = V_C$	<sub>C</sub> , 5.5V			1.0	10	μΑ
V <sub>IH</sub>	High Level Enable Voltage			SD	2.0			٧
VIL	Low Level Enable Voltage				GND		0.8	٧
I <sub>IH</sub>	High Level Enable Current	$2.0V \leq V_{IN} \leq 5.5V$	0°C to +85°C				+ 2.0	μΑ
			-40°C to 0°C				+ 4.0	μΑ
IIL	Low Level Enable Current	$\text{GND} \leq \text{V}_{\text{IN}} \leq \text{0.8V}$			-2.0			μΑ
DRIVER CH	HARACTERISTICS							
V <sub>IH</sub>	High Level Input Voltage		D <sub>IN</sub>		2.0			V
VIL	Low Level Input Voltage				GND		0.8	٧
t <sub>IH</sub>	High Level Input Current	$2.0V \leq V_{IN} \leq 5.5V$					+ 1.0	μΑ
I <sub>IL</sub>	Low Level Input Current	$\text{GND} \leq \text{V}_{\text{IN}} \leq \text{0.8V}$			-1.0			μΑ
V <sub>OH</sub>	High Level Output Voltage	$R_L = 3 k\Omega$			+ 5.0	+ 7.1		V
VoL	Low Level Output Voltage					-6.3	-5.0	٧
I <sub>OS+</sub>	Output High Short Circuit Current	V <sub>O</sub> = 0V, V <sub>IN</sub> = 0.8V (Note 7)		-40	-16.5	-8	mA	
I <sub>OS</sub> -	Output Low Short Circuit Current	V <sub>O</sub> = 0V, V <sub>IN</sub> = 2.0V (Note 7)			6	12.3	40	mA
Ro	Output Resistance	$-2V \le V_O \le +2V, V_{CC} = GND = 0V$			300			Ω

Symbol	Parameter	Conditions	Min	Тур	Max	Units
RECEIVER (	CHARACTERISTICS (Note 4)		·			
V <sub>TH</sub>	Input High Threshold Voltage	R1-R5, SD = 0.8V		1.4	2.4	٧
		R5, 2.0V ≤ SD ≤ 5.5V		2.0	2.8	٧
V <sub>TL</sub>	Input Low Threshold Voltage	R1-R5, SD = 0.8V	0.4	1.1		٧
		R5, 2.0V ≤ SD ≤ 5.5V	0.1	0.5		٧
$V_{HY}$	Hysteresis		50	300		m∨
RIN	Input Resistance	$V_{IN} = \pm 3V \text{ to } \pm 15V$	3.0	3.8	7.0	kΩ
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = +15V	2.14		5.0	mA
		$\Lambda^{IN} = +3\Lambda$	0.43		1.0	mA
		$V_{IN} = -3V$	-1.0		-0.43	mA
		$V_{IN} = -15V$	-5.0		-2.14	mA
V <sub>OH</sub>	High Level Output Voltage	$V_{IN} = -3V$ , $I_{OH} = -1$ mA	2.4	3.1		٧
		$V_{IN} = -3V$ , $I_{OH} = -100 \mu A$	2.8	3.28		٧
VoL	Low Level Output Voltage	$V_{IN} = +3V, I_{OL} = +2 \text{ mA}$		0.23	0.4	٧

Switching Characteristics Over recommended operating conditions, SD = 0.8V, unless otherwise specified. (Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
DRIVER CH	ARACTERISTICS					
t <sub>PLH</sub>	Propagation Delay LOW to HIGH	$R_L = 3 k\Omega$	0.1	0.6	1.0	μs
t <sub>PHL</sub>	Propagation Delay HIGH to LOW	C <sub>L</sub> = 50 pF	0.1	0.6	1.0	μs
tsK	Skew  tpLH-tpHL	(Figures 1 and 2)		0	0.2	μs
SR1	Output Slew Rate	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega, C_L = 50 \text{ pF} (Figure 2)$	4	13	30	V/µs
SR2	Output Slew Rate	$R_L = 3 \text{ k}\Omega$ , $C_L = 2500 \text{ pF}$ (Figure 2)	4	10	30	V/µs
tpLS	Propagation Delay LOW to SD	(Figures 5 and 6) R <sub>L</sub> = 3 kΩ C <sub>L</sub> = 50 pF		0.48		ms
t <sub>PSL</sub>	Propagation Delay SD to LOW			1.88		ms
t <sub>PHS</sub>	Propagation Delay HIGH to SD			0.62		ms
t <sub>PSH</sub>	Propagation Delay SD to HIGH			1.03		ms
RECEIVER	CHARACTERISTICS					
t <sub>PLH</sub>	Propagation Delay LOW to HIGH	C <sub>L</sub> = 50 pF (Figures 3 and 4)	0.1	0.4	1.0	μs
t <sub>PHL</sub>	Propagation Delay HIGH to LOW		0.1	0.6	1.0	μs
tsk	Skew  tpLH-tpHL			0.2	0.8	μs
tpLS	Propagation Delay LOW to SD	$(Figures 7 \text{ and } 8)$ $R_L = 1 \text{ k}\Omega$ $C_L = 50 \text{ pF}$ $R1-R4 \text{ Only}$		0.13		μs
t <sub>PSL</sub>	Propagation Delay SD to LOW			1.0		μs
t <sub>PHS</sub>	Propagation Delay HIGH to SD			0.19		μs
tpsH	Propagation Delay SD to HIGH			0.58		μs

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Typical values are given for  $V_{\rm CC}=3.3V$  and  $T_{\rm A}=\pm25^{\circ}{\rm C}.$ 

Note 3: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.

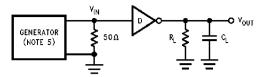
Note 4: Receiver characteristics are guaranteed for SD = 0.8V. When SD = 2.0V, receiver five (R5) is active and meets receiver parameters in SHUTDOWN (SD) mode, unless otherwise specified.

Note 5: Generator characteristics for driver input: f = 64 kHz (128 kbits/sec),  $t_f = t_f < 10$  ns,  $V_{IH} = 3V$ ,  $V_{IL} = 0V$ , duty cycle = 50%.

Note 6: Generator characteristics for receiver input: f = 64 kHz (128 kbits/sec), t<sub>r</sub> = t<sub>f</sub> = 200 ns, V<sub>IH</sub> = 3V, V<sub>IL</sub> = -3V, duty cycle = 50%.

Note 7: Only one driver output shorted at a time.

#### **Parameter Measurement Information**



TL/F/11734-3
FIGURE 1. Driver Propagation Delay and Slew Rate Test Circuit

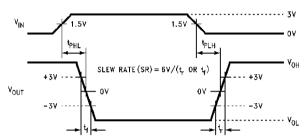


FIGURE 2. Driver Propagation Delay and Slew Rate Timing

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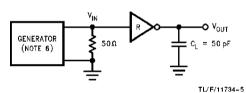


FIGURE 3. Receiver Propagation Delay Test Circuit

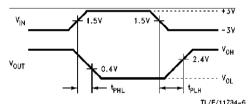


FIGURE 4. Receiver Propagation Delay Timing

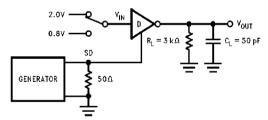


FIGURE 5. Driver SHUTDOWN (SD) Delay Test Circuit

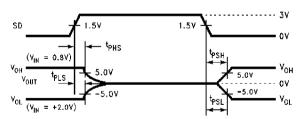


FIGURE 6. Driver SHUTDOWN (SD) Delay Timing

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#### Parameter Measurement Information (Continued)

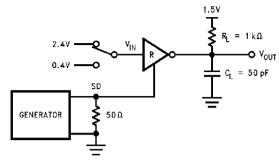


FIGURE 7. Receiver SHUTDOWN (SD) Delay Test Circuit

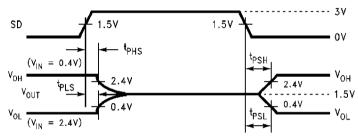


FIGURE 8. Receiver SHUTDOWN (SD) Delay Timing

TL/F/11734-10

TL/F/11734-9

#### **Pin Descriptions**

 $V_{CC}$  (Pin 3). Power supply pin for the device,  $\pm 3.3 \text{V}$  ( $\pm 0.3 \text{V}$ ).

V $^+$  (Pin 1). Positive supply for TIA/EIA-232-E drivers. Recommended external capacitor—0.47  $\mu$ F (16V). This supply is not intended to be loaded externally.

**V** $^-$  (Pin 25). Negative supply for TIA/EIA-232-E drivers. Recommended external capacitor—0.47  $\mu$ F (16V). This supply is not intended to be loaded externally.

C1+, C1- (Pins 6, 24). External capacitor connection pins. Recommended capacitor—0.47  $\mu$ F (6.3V).

C2+, C2- (Pins 2, 4). External capacitor connection pins. Recommended capacitor—0.47  $\mu F$  (16V).

C3+, C3- (Pins 28, 26). External capacitor connection pins. Recommended capacitor—0.47  $\mu$ F (6.3V).

SHUTDOWN (SD) (Pin 23). A High on the SHUTDOWN pin will lower the total  $I_{\rm CC}$  current to less than 10  $\mu$ A, providing a low power state. In this mode receiver R5 remains active. The SD pin should be driven or tied low (GND) to disable the shutdown mode.

**D<sub>IN</sub> 1-3 (Pins 7, 8, 9).** Driver input pins are JEDEC 3.3V standard compatible.

**D<sub>OUT</sub> 1-3 (Pins 22, 21, 20).** Driver output pins conform to TIA/EIA-232 -E levels.

**R**<sub>IN</sub> 1–5 (Pins 19, 18, 17, 16, 15). Receiver input pins accept TIA/EIA-232-E input voltages ( $\pm$ 25V). Receivers guarantees hysteresis of TBD mV. Unused receiver input pins may be left open. Internal input resistor (5 k $\Omega$ ) pulls input LOW, providing a failsafe HIGH output.

R<sub>OUT</sub> 1-5 (Pins 10, 11, 12, 13, 14). Receiver output pins are JEDEC 3.3V standard compatible.

GND (Pin 27), Ground Pin.

#### **Application Information**

#### 9-Pin SERIAL PORT APPLICATION

In a typical Data Terminal Equipment (DTE) to Data Circuit-Terminating Equipment (DCE) 9-pin de-facto interface implementation, 2 data lines and 6 control lines are required. The data lines are TXD and RXD and the control lines are RTS, DTR, DSR, DCD, CTS and RI. The DS14C335 is a 3 x 5 Driver/Receiver and offers a single chip solution for the DTE interface as shown in *Figure 9*.

Ring Indicator (RI) is used to inform the DTE that an incoming call is coming from a remote DCE. When the DS14C335 is in SHUTDOWN (SD) mode, receiver five (R5) remains active and monitors RI circuit. This active receiver (R5) alerts the DTE to switch the DS14C335 from SHUTDOWN to active mode.

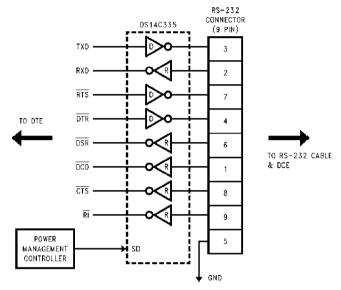


FIGURE 9. Typical DTE Application

TL/F/11734-11

#### Application Information (Continued)

#### MOUSE DRIVING

The DS14C335 was tested for drive current under the following mouse driving conditions:

- Two driver outputs set at V<sub>OH</sub> and their outputs were tied together (paralleled), sourcing current to supply the V+ terminal of the mouse electronics
- One driver output set at V<sub>OL</sub> to sink the current from the V – terminal of the mouse electronics
- · One receiver was used to accept data from the mouse
- Power Supply Voltage (V<sub>CC</sub>): 3.0V to 3.6V

Completion of the testing (performed by National's Data Transmission Applications Group and a major PC manufacturer) concluded that the DS14C335 and it's DC-DC Convertor supplied adequate drive capability to power a typical PC mouse. The mouse tested was specified with the following conditions:

10 mA at +6V 5.0 mA at -6V

Since driver current is limited, it is recommended that newer lower power mice be specified for battery powered applications. Using older high power mice is wasteful of precious battery charge.

#### **EXTERNAL DC-DC CONVERTOR COMPONENTS**

The DS14C335 with it's unique DC-DC Convertor triples the power supply voltage (3.0V) to  $\pm$ 9.3V and then inverts it to a -9V potential. This unique convertor **ONLY** requires 5 external surface mount 0.47  $\mu\text{F}$  capacitors. The five identical components were chosen to simplify PCB layout and the procurement of components. The DS14C335's DC-DC Convertor also provides a larger signal swing (higher at RS-232 standard data rates) which translates to more noise margin for the rejection of ground potential differences, induced

noise, and crosstalk compared to other DC-DC convertor schemes which only provide limited signal swing and limited noise margin.

#### **DC-DC CONVERTOR CAPACITORS**

The use of polarized capacitors is not required. However, if they are used, the polarity indicated in the DS14C335 Functional Diagram must be honored for proper operation. Surface mount capacitors or ceramic capacitors may be used, however, for optimal efficiency, capacitors with a low effective series resistance (ESR) should be used. Values in the low Ohms( $\Omega$ ) is normally acceptable.

#### INTEROPERATION WITH + 5V UARTS

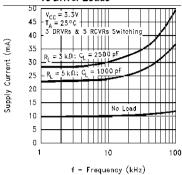
The DS14C335 provides full RS-232 driver output levels and a single chip solution for the popular 9-pin defacto serial port. This device may be used in either pure +3V applications or mixed power supplied +3V/+5V applications. The Driver Input (DIN) and ShutDown (SD) input pins can directly accept full +5V levels without the need for any external components. The Receiver Output (ROUT) is specified at 2.4V minimum while sourcing 1 mA. This level is compatible with standard TTL thresholds. For a complete discussion on "Interoperation of the DS14C335 with +5V UARTs" please see National Application Note AN-876.

#### POWER DISSIPATION IN REAL RS-232 APPLICATIONS

The DS14C335 DC-DC Convertor uses special circuitry that helps limit the increase in power supply current as frequency increases. A complete description of power dissipation and calculations for RS-232 applications can be found in National Application Note AN-914 titled "Understanding Power Requirements in RS-232 Applications". Typical performance curves are also located in this datasheet for quick reference.

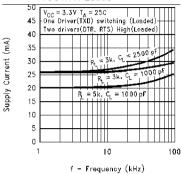
### **Typical Performance Characteristics**

# Supply Current vs Frequency vs Driver Loads



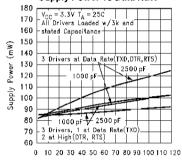
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# Supply Current vs Frequency vs Driver Loads



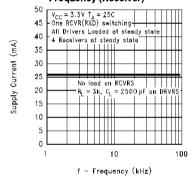
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#### Supply Power vs Data Rate



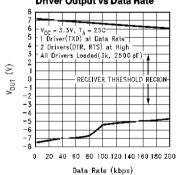
Data Rate (kbps) TL/F/11734-14

#### Supply Current vs Frequency (Receiver)



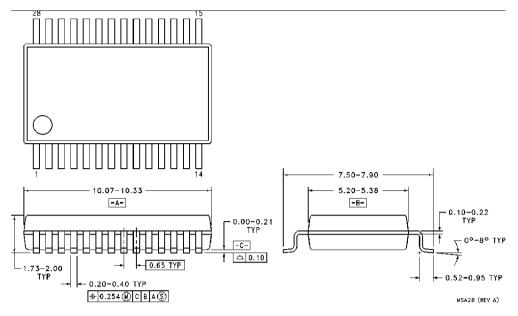
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#### **Driver Output vs Data Rate**



TL/F/11734-16

#### Physical Dimensions inches (millimeters)



Order Number DS14C335MSA or DS14C335TMSA NS Package Number MSA28

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National Semiconductor National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

http://www.national.com

National Semiconductor Europe

Fax: +49 (0) 180-530 85 86 Fax: +49 (0) 180-530 85 86
Email: europe support@ ssc.com
Deutsch Tel: +49 (0) 180-530 85 85
Engish Tel: +49 (0) 180-532 78 32
Français Tel: +49 (0) 180-534 16 80
Italiano Tel: +49 (0) 180-534 16 80 National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block, Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor Japan Ltd. Tel: 81-043-299-2308 Fax: 81-043-299-2408

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